

UNITED STATES PATENT AND TRADEMARK OFFICE

UNITED STATES DEPARTMENT OF COMMERCE United States Patent and Trademark Office Address: COMMISSIONER FOR PATENTS P.O. Box 1450 Alexandria, Virginia 22313-1450 www.uspto.gov

APPLICATION N	0. 1	FILING DATE	FIRST NAMED INVENTOR	ATTORNEY DOCKET NO.	CONFIRMATION NO.
10/718,666	10/718,666 11/24/2003		Ming-Cheng Chang	CHAN3232/EM	1606
23364	7590	01/14/2005		EXAMINER	
	& THOM.	•	KANG, DONGHEE		
625 SLATERS LANE FOURTH FLOOR				ART UNIT	PAPER NUMBER
ALEXANDRIA, VA 22314				2811	
				DATE MAILED: 01/14/200:	5

Please find below and/or attached an Office communication concerning this application or proceeding.

			1/2/				
	Application No.	Applicant(s)					
Office Action Summary	10/718,666	CHANG, MING-C	CHANG, MING-CHENG				
Office Action Summary	Examiner	Art Unit					
The MAN INO DATE of this control of	Donghee Kang	2811					
The MAILING DATE of this communication ap Period for Reply	opears on the cover shee	t with the correspondence ad	Idress				
A SHORTENED STATUTORY PERIOD FOR REPORTED MAILING DATE OF THIS COMMUNICATION - Extensions of time may be available under the provisions of 37 CFR 1 after SIX (6) MONTHS from the mailing date of this communication. - If the period for reply specified above is less than thirty (30) days, a relif NO period for reply is specified above, the maximum statutory period. - Failure to reply within the set or extended period for reply will, by statut Any reply received by the Office later than three months after the mailing earned patent term adjustment. See 37 CFR 1.704(b).	136(a). In no event, however, ma ply within the statutory minimum o d will apply and will expire SIX (6) I te, cause the application to becom	ny a reply be timely filed If thirty (30) days will be considered timel MONTHS from the mailing date of this c BABANDONED (35 U.S.C. § 133).	ly. ommunication.				
Status							
1) Responsive to communication(s) filed on 24	November 2003.						
	is action is non-final.						
Disposition of Claims							
4) ☐ Claim(s) 1-6 is/are pending in the application 4a) Of the above claim(s) is/are withdres 5) ☐ Claim(s) is/are allowed. 6) ☐ Claim(s) 1-6 is/are rejected. 7) ☐ Claim(s) is/are objected to. 8) ☐ Claim(s) are subject to restriction and/	awn from consideration.						
Application Papers							
9)☐ The specification is objected to by the Examin	er.						
I0)☐ The drawing(s) filed on is/are: a)☐ accepted or b)☐ objected to by the Examiner.							
Applicant may not request that any objection to the	,	• • • • • • • • • • • • • • • • • • • •					
Replacement drawing sheet(s) including the corre	•		• •				
Priority under 35 U.S.C. § 119							
12) Acknowledgment is made of a claim for foreig a) All b) Some * c) None of: 1. Certified copies of the priority documer 2. Certified copies of the priority documer 3. Copies of the certified copies of the pri application from the International Burea * See the attached detailed Office action for a list	nts have been received. nts have been received i ority documents have be au (PCT Rule 17.2(a)).	n Application No een received in this National	Stage				
Attachment(s)		·					
1) Notice of References Cited (PTO-892)		ew Summary (PTO-413) No(s)/Mail Date					
 2) Notice of Draftsperson's Patent Drawing Review (PTO-948) 3) Information Disclosure Statement(s) (PTO-1449 or PTO/SB/08 Paper No(s)/Mail Date 		of Informal Patent Application (PTC	O-152)				

Application/Control Number: 10/718,666

Art Unit: 2811

DETAILED ACTION

Claim Rejections - 35 USC § 102

1. The following is a quotation of the appropriate paragraphs of 35 U.S.C. 102 that form the basis for the rejections under this section made in this Office action:

A person shall be entitled to a patent unless -

- (b) the invention was patented or described in a printed publication in this or a foreign country or in public use or on sale in this country, more than one year prior to the date of application for patent in the United States.
- 2. Claims 1-6 are rejected under 35 U.S.C. 102(b) as being anticipated by Perng et al. (US 6,090,661).

Re claim 1, Perng et al. teach in Figs.1 a deep trench structure of semiconductor device, said semiconductor device having a plurality of active areas (1 & 3), said deep trench structure (19) characterized in that said deep trench communicates with two different active areas. See also Col.5, line 6-Col.6, line 24.

Re claim 2, Perng et al. teach the cross section of said deep trench communicates with two different active areas.

Re claim 3, Perng et al. teach said two different active areas communicated by said deep trench are respectively connected with two adjacent bit lines.

Re claim 4, Perng et al. teach a semiconductor memory device comprising (Fig.1):

A plurality of bit lines; aplurality of gates crossing with said bit lines; a plurality of active areas, each of which is connected to one of said bit lines; a plurality of deep trenches, at least one of which communicates with two different active areas. See also Col.5, line 6-Col.6, line 24.

Art Unit: 2811

Re claim 5, Perng et al. teach the cross section of said deep trench communicates with two different active areas.

Re claim 6, Perng et al. teach said two different active areas communicated by said deep trench are respectively connected with two adjacent bit lines.

Conclusion

3. Any inquiry concerning this communication or earlier communications from the examiner should be directed to Donghee Kang whose telephone number is 571-272-1656. The examiner can normally be reached on Monday through Friday.

If attempts to reach the examiner by telephone are unsuccessful, the examiner's supervisor, Eddie C. Lee can be reached on 571-272-1732. The fax phone number for the organization where this application or proceeding is assigned is 703-872-9306.

Information regarding the status of an application may be obtained from the Patent Application Information Retrieval (PAIR) system. Status information for published applications may be obtained from either Private PAIR or Public PAIR. Status information for unpublished applications is available through Private PAIR only. For more information about the PAIR system, see http://pair-direct.uspto.gov. Should you have questions on access to the Private PAIR system, contact the Electronic Business Center (EBC) at 866-217-9197 (toll-free).

Donghee Kang, Ph.D. Primary Examiner Art Unit 2811

Camphonle

dhk